TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC4514AP

4-to-16 Line Decoder/Latch

The TC74HC4514A are high speed CMOS 4-LINE TO 16-LINE DECODER WITH LATCHED INPUTs fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The selected output is enabled by a low on the inhibit input (INHIBIT). A binary code stored in the four input latches (A thru D) is decided and provides a high level at the corresponding one of sixteen outputs. When the INHIBIT is held low, all outputs are kept low however, the latch function is available.

The data applied to the data inputs are transferred to the outputs of latches when the strobe input is held high. When the strobe input is taken low, the data is retained at the subjut of the



Weight: 1.50 g (typ.)

strobe input is taken low, the data is retained at the output of the latches.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 18 \text{ ns}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \pmod{at Ta} = 25^{\circ}C$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: |IOH| = IOL = 4 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 to 6 V
- Pin and function compatible with 4514B

Pin Assignment





IEC Logic Symbol





Truth Table

	h	Selected Outputs			
Inhibit	А	В	С	D	"H"
L	L	L	L	L	S0
L	Н	L	L	L	S1
L	L	Н	L	L	S2
L	Н	Н	L	L	S3
L	L	L	Н	L	S4
L	Н	L	Н	L	S5
L	L	Н	Н	L	S6
L	Н	Н	Н	L	S7
L	L	L	L	Н	S8
L	Н	L	L	Н	S9
L	L	Н	L	Н	S10
L	Н	Н	L	Н	S11
L	L	L	Н	Н	S12
L	Н	L	Н	Н	S13
L	L	Н	Н	Н	S14
L	Н	Н	Н	Н	S15
Н	Х	Х	Х	Х	All Outputs "L"

X: Don't care

STROBE = "H"; Refer to truth table

 $\mathsf{STROBE} = \mathsf{``L"}$



Data at the negative going transition of strobe shall be provided on each output while strobe is held low.

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System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	–0.5 to 7	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT} -0.5 to V _{CC} + 0.5		V
Input diode current	IIК	±20	mA
Output diode current	IOK	±20	mA
DC output current	irrent I _{OUT} ±25		mA
DC V _{CC} /ground current	ICC	I _{CC} ±50	
Power dissipation	PD	500 (DIP) (Note 2)	mW
Storage temperature	T _{stg}	–65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65° C. From Ta = 65 to 85° C a derating factor of -10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2 to 6	V
Input voltage	V _{IN}	0 to V _{CC}	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
		0 to 1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0 to 500 ($V_{CC} = 4.5 \text{ V}$)	ns
		0 to 400 ($V_{CC} = 6.0 \text{ V}$)	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition V _{CC} (V)			Ta = 25°C			Ta = -40 to 85°C		Unit	
Characteriotice	Cymbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	C	
		_		2.0	1.50		_	1.50	_		
High-level input voltage	VIH			4.5	3.15	—	—	3.15	—	V	
				6.0	4.20	—	_	4.20	_		
				2.0	_	_	0.50	_	0.50		
Low-level input voltage	VIL	—		4.5	—	—	1.35	_	1.35	V	
				6.0	—	—	1.80	—	1.80		
	Vон	V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9	_		
			$I_{OH} = -20 \ \mu A$	4.5	4.4	4.5	—	4.4	—		
High-level output voltage				6.0	5.9	6.0	_	5.9	_	V	
Ŭ			I _{OH} = -4 mA	4.5	4.18	4.31		4.13			
			I _{OH} = -5.2 mA	6.0	5.68	5.80	—	5.63	—		
		VIN = VIH or		2.0	—	0.0	0.1	_	0.1		
			I _{OL} = 20 μA	4.5	—	0.0	0.1	—	0.1		
Low-level output voltage	V _{OL}			6.0	—	0.0	0.1	—	0.1	V	
Ũ		VIL	I _{OL} = 4 mA	4.5	_	0.17	0.26	_	0.33		
			I _{OL} = 5.2 mA	6.0	—	0.18	0.26	—	0.33	0.33	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0			±0.1	_	±1.0	μΑ	
Quiescent supply current	ICC	$V_{IN} = V_C$	_C or GND	6.0	_	_	4.0	_	40.0	μA	

Timing Requirements (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Test Condition			Ta = -40 to 85°C	Unit	
			V _{CC} (V)	Тур.	Limit	Limit		
Minimum pulse width			2.0	_	75	95		
(STROBE)	t _{W (H)}	—	4.5	—	15	19	ns	
(STRUBE)			6.0	—	13	16		
Minimum set-up time	ts	_	2.0		50	65	ns	
·			4.5	—	10	13		
(DATA)			6.0	_	9	11		
Minimum hold time			2.0		5	5		
(DATA)	t _h	—	4.5	—	5	5	ns	
			6.0	—	5	5		

AC Characteristics ($C_L = 15 \text{ pF}$, $V_{CC} = 5 \text{ V}$, $Ta = 25^{\circ}C$, input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t _{TLH} t _{THL}	_		4	8	ns
Propagation delay time (DATA-Sn)	t _{pLH} t _{pHL}	—		18	30	ns
Propagation delay time (STROBE-Sn)	t _{pLH} t _{pHL}	_	_	20	30	ns
Propagation delay time (INHIBIT-Sn)	t _{pLH} t _{pHL}	_	_	16	30	ns

AC Characteristics (C_L = 50 pF, input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
onaractenstics	Gymbol		V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
	4		2.0		30	75	_	95	
Output transition time	t _{TLH}	—	4.5	—	8	15	—	19	ns
	t _{THL}		6.0	—	7	13	—	16	
Propagation delay	+		2.0	_	65	175	_	220	
time	t _{pLH} t	—	4.5	—	22	35	—	44	ns
(DATA-Sn)	t _{pHL}		6.0	—	19	30	—	37	
Propagation delay	+	4	2.0	_	75	175	_	220	
time	t _{pLH} t	—	4.5	—	24	35	—	44	ns
(STROBE-Sn)	t _{pHL}		6.0		20	30	_	37	
Propagation delay	t		2.0	—	60	175	_	220	
time	t _{pLH} t	—	4.5	—	20	35	—	44	ns
(INHIBIT-Sn)	t _{pHL}		6.0	—	17	30	—	37	
Input capacitance	C _{IN}	_		_	5	10		10	pF
Power dissipation	C _{PD}				61				pF
capacitance	(Note)				01				μr

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC} (opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

TOSHIBA

Package Dimensions

DIP24-P-300-2.54

Unit : mm



Weight: 1.50 g (typ.)

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20070701-EN GENERAL

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